

# PHOTOCOUPLER **PS2601,PS2602,PS2601L,PS2602L**

# HIGH ISOLATION VOLTAGE 6-PIN PHOTOCOUPLER

-NEPOC<sup>™</sup> Series-

#### **DESCRIPTION**

The PS2601, PS2601L, PS2602L are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor in a plastic DIP (Dual In-line Package).

The PS2601L, PS2602L are lead bending type (Gull-wing) for surface mount.

#### **FEATURES**

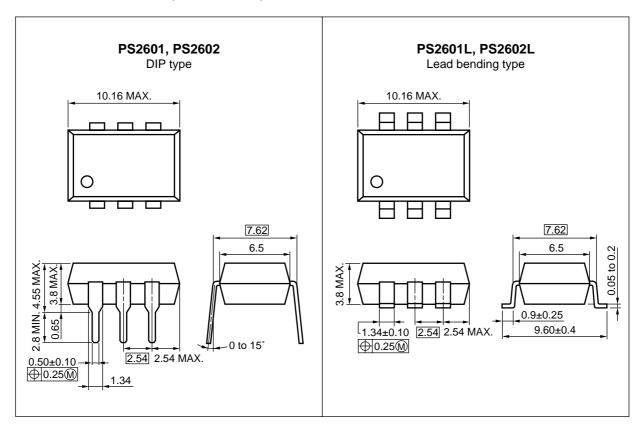
- High Isolation voltage (BV = 5 000 Vr.m.s.)
- High collector to emitter voltage (VcEo = 80 V)
- High-speed switching ( $t_r = 3 \mu s$  TYP.,  $t_f = 5 \mu s$  TYP.)
- High current transfer ratio (CTR = 300 % TYP.)
- UL approved: File No. E72422 (S)
- · Ordering number of taping product: PS2601L-E3, E4, PS2602L-E3, E4

#### ★ APPLICATIONS

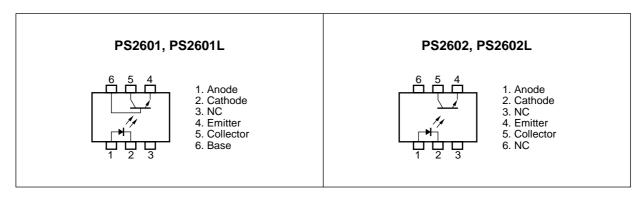
- · Power supply, SSR
- · Telephone, FAX
- AC/DC line interface
- · Electric home appliances

The information in this document is subject to change without notice.

#### **★ PACKAGE DIMENSIONS (in millimeters)**



#### PIN CONNECTIONS (TOP VIEW)



#### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	80	mA
	Reverse Voltage	VR	6.0	V
	Power Dissipation Derating	∆P₀/°C	1.5	mW/°C
	Power Dissipation	PD	150	mW
	Peak Forward Current <sup>*1</sup>	IFP	1	Α
Transistor	Collector to Emitter Voltage	Vceo	80	V
	Emitter to Collector Voltage	Veco	7	V
	Collector Current	lc	50	mA
	Power Dissipation Derating	∆Pc/°C	1.5	mW/°C
	Power Dissipation	Pc	150	mW
Isolation Voltage <sup>2</sup>		BV	5 000	Vr.m.s.
Operating Ambient Temperature		TA	-55 to +100	°C
Storage Temperature		T <sub>stg</sub>	−55 to +150	°C

<sup>\*1</sup> PW = 100  $\mu$ s, Duty Cycle = 1 %

<sup>\*2</sup> AC voltage for 1 minute at T<sub>A</sub> = 25 °C, RH = 60 % between input and output

#### ELECTRICAL CHARACTERISTICS (TA = 25 °C)

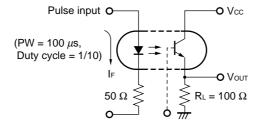
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.1	1.4	V
	Reverse Current	lr	V <sub>R</sub> = 5 V			5.0	μΑ
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		30		pF
Transistor	Collector to Emitter Dark Current	Iceo	Vce = 80 V, I <sub>F</sub> = 0 mA			100	nA
	DC Current Gain*1	hfe	Ic = 2 mA, VcE = 5 V		700		
Coupled	Current Transfer Ratio (Ic/IF) '2	CTR	I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V	80	300	600	%
	Collector Saturation Voltage	VCE (sat)	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 2 mA			0.3	V
	Isolation Resistance	Rı-o	Vi-o = 1.0 kVpc	10 <sup>11</sup>			Ω
	Isolation Capacitance	C <sub>I-O</sub>	V = 0 V, f = 1.0 MHz		0.6		pF
	Rise Time *3	tr	$Vcc = 5 \text{ V}, \text{ Ic} = 2 \text{ mA}, \text{ RL} = 100 \Omega$		3		μs
	Fall Time*3	t <sub>f</sub>			5		

\*1 PS2601, PS2601L only

\*2 CTR rank

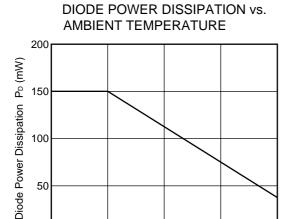
K: 300 to 600 (%) L: 200 to 400 (%) M: 80 to 240 (%)

\*3 Test circuit for switching time



0

#### **★** TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)



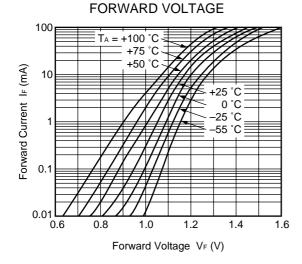
FORWARD CURRENT vs.

50

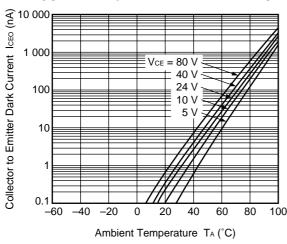
Ambient Temperature TA (°C)

75

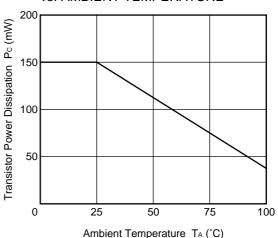
100



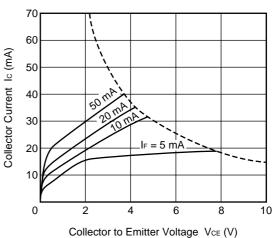
COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE



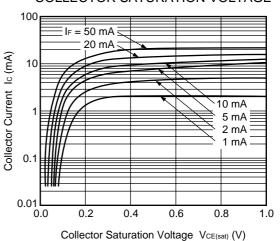
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



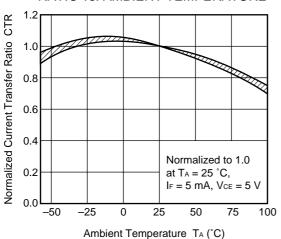
COLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGE



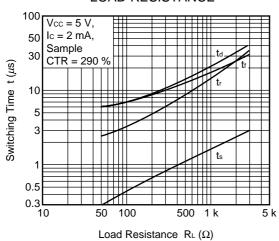
COLLECTOR CURRENT vs.
COLLECTOR SATURATION VOLTAGE



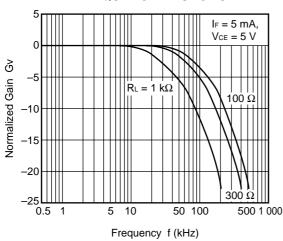
# NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



# SWITCHING TIME vs. LOAD RESISTANCE

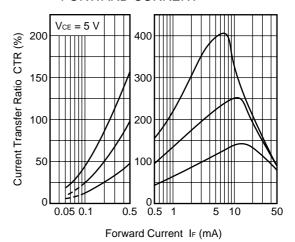


#### FREQUENCY RESPONSE

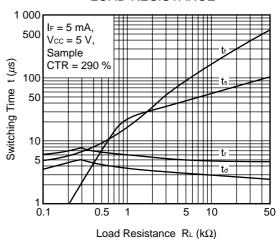


Remark The graphs indicate nominal characteristics.

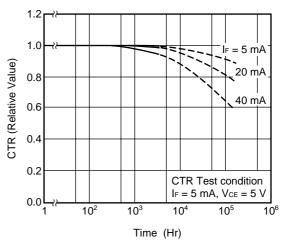
# CURRENT TRANSFER RATIO vs. FORWARD CURRENT



#### SWITCHING TIME vs. LOAD RESISTANCE



#### LONG TERM CTR DEGRADATION



#### RECOMMENDED SOLDERING CONDITIONS

#### (1) Infrared reflow soldering

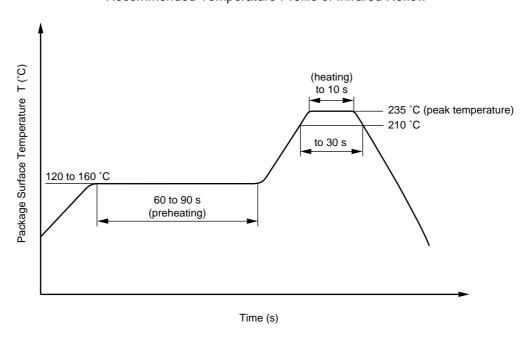
• Peak reflow temperature 235 °C (package surface temperature)

• Time of temperature higher than 210 °C 30 seconds or less

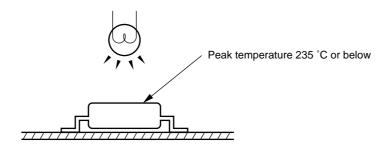
• Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

#### Recommended Temperature Profile of Infrared Reflow



Caution Please avoid removing the residual flux by water after the first reflow process.



#### (2) Dip soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt % is recommended.)

#### **CAUTION**

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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Anti-radioactive design is not implemented in this product.